



I'm not robot



I am not robot!

Improved transconductance 20N60C3 Product details. These devices have the high input impedance of a MOSFET and the low on-state conduction loss of a bipolar transistor The data contained in this document is exclusively intended for technically trained staff. These devices have the high input impedance of a MOSFET and the low on-state conduction loss of a bipolar transistor DescriptionA, V, UFS Series N-Channel IGBTResults. Type of Control Channel: N -Channel. Extreme dv/dt rated P-TO High peak current capability. Feature. Worldwide best. Description. Image This family of MOS gated high voltage switching devices combining the best features of MOSFETs and bipolar transistors. DescriptionA, V, UFS Series N-Channel IGBTResults. This family of MOS gated high voltage switching devices combining the best features of MOSFETs and bipolar transistors. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application Part NumberN60C3, SPP20N60CFunction: Cool MOS Power Transistor. New revolutionary high voltage technology. PartN60CDescription: Cool MOS Power Transistor. PdⓈMaximum Power DissipationW 20N60C3 Intersil Corporation N-Channel IGBT. Feature. File SizeKbytes. File SizeKbytes. Part: HGTG20N60CDatasheet: Kb/8P. See the preview image and the PDF file for more information. Ultra low gate charge. Package: PG-TOFP, PG-TO, PG-TO Manufacturer: Infineon Technologies. Periodic avalanche DownloadN60C3 Datasheet. This family of MOS gated high voltage switching devices combining the best features of MOSFETs and bipolar transistors. Data Sheet HGTG20N60C3, HGTP20N60C3, HGT1S20N60C3S emberA, V, UFS Series N-Channel PartN60CDescriptionA, V, UFS Series N-Channel IGBT. Manufacturer: Fairchild Semiconductor Equivalent. Worldwide best. Part: HGTG20N60C3 Datasheet pdf. Manufacturer: Intersil CorporationSPP20N60C3, SPB20N60C3 Cool MOS™ Power Transistor. New revolutionary high voltage technology. Manufacturer: Infineon Technologies AG 20N60C3 Power Transistor Components datasheet pdf data sheet FREE from Datasheet (data sheet) search for integrated circuits (ic), Datasheet: Kb/8P. Type Designator: SPP20N60CType of Transistor: MOSFET. Manufacturer: Fairchild Semiconductor. Ultra low gate charge. 20N60C3 Product details. Periodic avalanche rated. These devices have SPP20N60C3, SPB20N60C3 Cool MOS™ Power Transistor.